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Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

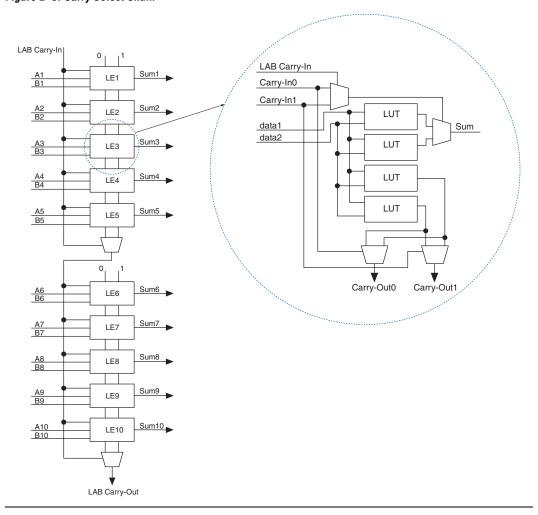
Details	
Product Status	Obsolete
Number of LABs/CLBs	598
Number of Logic Elements/Cells	5980
Total RAM Bits	92160
Number of I/O	185
Number of Gates	-
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-BGA
Supplier Device Package	256-FBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep1c6f256c6

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Figure 2–8 shows the carry-select circuitry in a LAB for a 10-bit full adder. One portion of the LUT generates the sum of two bits using the input signals and the appropriate carry-in bit; the sum is routed to the output of the LE. The register can be bypassed for simple adders or used for accumulator functions. Another portion of the LUT generates carry-out bits. A LAB-wide carry-in bit selects which chain is used for the addition of given inputs. The carry-in signal for each chain, carry-in0 or carry-in1, selects the carry-out to carry forward to the carry-in signal of the next-higher-order bit. The final carry-out signal is routed to an LE, where it is fed to local, row, or column interconnects.

Figure 2-8. Carry Select Chain



is not available in the true dual-port mode. Mixed-width configurations are also possible, allowing different read and write widths. Tables 2–3 and 2–4 summarize the possible M4K RAM block configurations.

Table 2–3. M4K RAM Block Configurations (Simple Dual-Port)												
Read Port		Write Port										
NEAU FUIL	4K × 1	2K × 2	1K × 4	512 × 8	256 × 16	128 × 32	512 × 9	256 × 18	128 × 36			
4K × 1	✓	✓	✓	~	✓	✓	_	_	_			
2K × 2	✓	✓	✓	✓	✓	✓	_	_	_			
1K × 4	~	✓	✓	~	✓	✓	_	_	_			
512 × 8	✓	✓	✓	~	✓	✓	_	_	_			
256 × 16	~	✓	✓	~	✓	✓	_	_	_			
128 × 32	✓	✓	✓	~	✓	✓	_	_	_			
512 × 9	_	_	_	_	_	_	✓	~	✓			
256 × 18	_	_	_	_	_	_	✓	~	✓			
128 × 36	<u> </u>	_	_	_	_	_	✓	✓	✓			

Table 2–4. M4K RAM Block Configurations (True Dual-Port)											
Port A		Port B									
	4K × 1	2K × 2	1K × 4	512 × 8	256 × 16	512 × 9	256 × 18				
4K × 1	✓	✓	✓	✓	✓	_	_				
2K × 2	✓	✓	✓	✓	✓	_	_				
1K × 4	✓	✓	✓	✓	✓	_	_				
512 × 8	✓	✓	✓	✓	✓	_	_				
256 × 16	✓	✓	✓	✓	✓	_	_				
512 × 9	_	_	_	_	_	✓	✓				
256 × 18	_	_	_	_	_	✓	✓				

When the M4K RAM block is configured as a shift register block, you can create a shift register up to 4,608 bits $(w \times m \times n)$.

Single-Port Mode

The M4K memory blocks also support single-port mode, used when simultaneous reads and writes are not required. See Figure 2–21. A single M4K memory block can support up to two single-port mode RAM blocks if each RAM block is less than or equal to 2K bits in size.

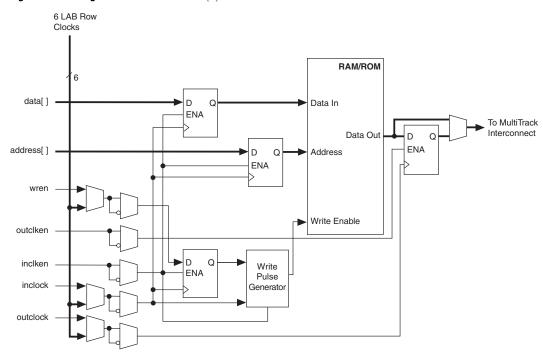


Figure 2–21. Single-Port Mode Note (1)

Note to Figure 2–21:

(1) Violating the setup or hold time on the address registers could corrupt the memory contents. This applies to both read and write operations.

Global Clock Network and Phase-Locked Loops

Cyclone devices provide a global clock network and up to two PLLs for a complete clock management solution.

Global Clock Network

There are four dedicated clock pins (CLK[3..0], two pins on the left side and two pins on the right side) that drive the global clock network, as shown in Figure 2–22. PLL outputs, logic array, and dual-purpose clock (DPCLK[7..0]) pins can also drive the global clock network.

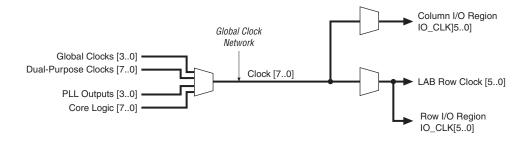
Dual-Purpose Clock Pins

Each Cyclone device except the EP1C3 device has eight dual-purpose clock pins, DPCLK[7..0] (two on each I/O bank). EP1C3 devices have five DPCLK pins in the 100-pin TQFP package. These dual-purpose pins can connect to the global clock network (see Figure 2–22) for high-fanout control signals such as clocks, asynchronous clears, presets, and clock enables, or protocol control signals such as TRDY and IRDY for PCI, or DQS signals for external memory interfaces.

Combined Resources

Each Cyclone device contains eight distinct dedicated clocking resources. The device uses multiplexers with these clocks to form six-bit buses to drive LAB row clocks, column IOE clocks, or row IOE clocks. See Figure 2–23. Another multiplexer at the LAB level selects two of the six LAB row clocks to feed the LE registers within the LAB.

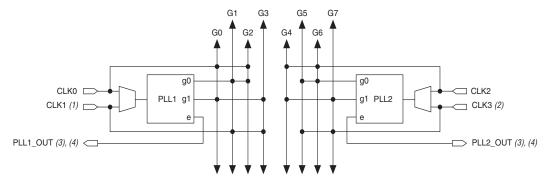
Figure 2-23. Global Clock Network Multiplexers



IOE clocks have row and column block regions. Six of the eight global clock resources feed to these row and column regions. Figure 2–24 shows the I/O clock regions.

Figure 2–26 shows the PLL global clock connections.

Figure 2-26. Cyclone PLL Global Clock Connections



Notes to Figure 2-26:

- (1) PLL 1 supports one single-ended or LVDS input via pins CLK0 and CLK1.
- (2) PLL2 supports one single-ended or LVDS input via pins CLK2 and CLK3.
- (3) PLL1_OUT and PLL2_OUT support single-ended or LVDS output. If external output is not required, these pins are available as regular user I/O pins.
- (4) The EP1C3 device in the 100-pin TQFP package does not support external clock output. The EP1C6 device in the 144-pin TQFP package does not support external clock output from PLL2.

Table 2–7 shows the global clock network sources available in Cyclone devices.

Table 2–7. Global Clock Network Sources (Part 1 of 2)									
Sou	rce	GCLKO	GCLK1	GCLK2	GCLK3	GCLK4	GCLK5	GCLK6	GCLK7
PLL Counter	PLL1 G0	_	✓	✓	_	_	_	_	_
Output	PLL1 G1	✓	_	_	✓	_	_	_	_
	PLL2 G0 (1)	_	_	_	_	_	✓	✓	_
	PLL2 G1 (1)	_	_	_	_	✓	_	_	✓
Dedicated	CLK0	✓	_	✓	_	_	_	_	_
Clock Input Pins	CLK1 (2)	_	✓	_	✓	_	_	_	_
	CLK2	_	_	_	_	✓	_	✓	_
	CLK3 (2)	_	_	_	_	_	✓	_	✓

Table 2–7. Global Clock Network Sources (Part 2 of 2)									
Sou	rce	GCLKO	GCLK1	GCLK2	GCLK3	GCLK4	GCLK5	GCLK6	GCLK7
Dual-Purpose	DPCLK0 (3)	_	_	_	✓	_	_	_	_
Clock Pins	DPCLK1 (3)	_	_	✓	_	_	_	_	_
	DPCLK2	✓	_	_	_	_	_	_	_
	DPCLK3	_	_	_	_	✓	_	_	_
	DPCLK4		_	_	_	_		✓	_
	DPCLK5 (3)	_	_	_	_	_	_	_	✓
	DPCLK6	_	_	_	_	_	✓	_	_
	DPCLK7	_	✓	_	_	_	_	_	_

Notes to Table 2-7:

- (1) EP1C3 devices only have one PLL (PLL 1).
- (2) EP1C3 devices in the 100-pin TQFP package do not have dedicated clock pins CLK1 and CLK3.
- (3) EP1C3 devices in the 100-pin TQFP package do not have the DPCLK0, DPCLK1, or DPCLK5 pins.

Clock Multiplication and Division

Cyclone PLLs provide clock synthesis for PLL output ports using $m/(n \times post$ scale counter) scaling factors. The input clock is divided by a pre-scale divider, n, and is then multiplied by the m feedback factor. The control loop drives the VCO to match $f_{\rm IN} \times (m/n)$. Each output port has a unique post-scale counter to divide down the high-frequency VCO. For multiple PLL outputs with different frequencies, the VCO is set to the least-common multiple of the output frequencies that meets its frequency specifications. Then, the post-scale dividers scale down the output frequency for each output port. For example, if the output frequencies required from one PLL are 33 and 66 MHz, the VCO is set to 330 MHz (the least-common multiple in the VCO's range).

Each PLL has one pre-scale divider, n, that can range in value from 1 to 32. Each PLL also has one multiply divider, m, that can range in value from 2 to 32. Global clock outputs have two post scale G dividers for global clock outputs, and external clock outputs have an E divider for external clock output, both ranging from 1 to 32. The Quartus II software automatically chooses the appropriate scaling factors according to the input frequency, multiplication, and division values entered.

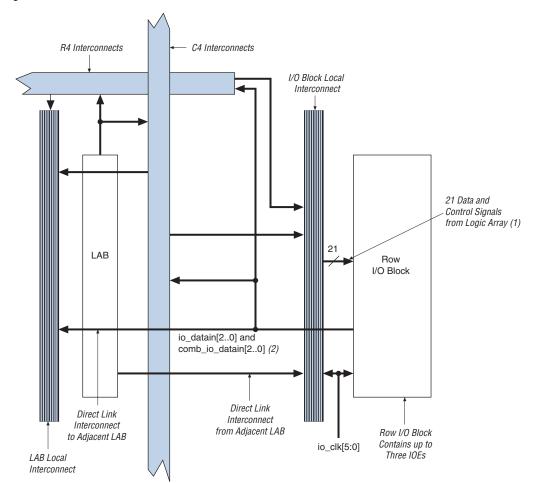


Figure 2-28. Row I/O Block Connection to the Interconnect

Notes to Figure 2–28:

- (1) The 21 data and control signals consist of three data out lines, io_dataout[2..0], three output enables, io_coe[2..0], three input clock enables, io_cce_in[2..0], three output clock enables, io_cce_out[2..0], three clocks, io_cclk[2..0], three asynchronous clear signals, io_caclr[2..0], and three synchronous clear signals, io_csclr[2..0].
- (2) Each of the three IOEs in the row I/O block can have one io_datain input (combinatorial or registered) and one comb_io_datain (combinatorial) input.

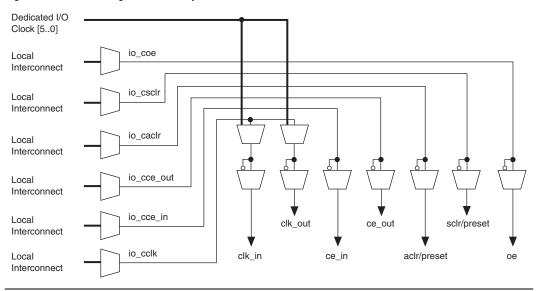


Figure 2-31. Control Signal Selection per IOE

In normal bidirectional operation, you can use the input register for input data requiring fast setup times. The input register can have its own clock input and clock enable separate from the OE and output registers. The output register can be used for data requiring fast clock-to-output performance. The OE register is available for fast clock-to-output enable timing. The OE and output register share the same clock source and the same clock enable source from the local interconnect in the associated LAB, dedicated I/O clocks, or the column and row interconnects. Figure 2–32 shows the IOE in bidirectional configuration.

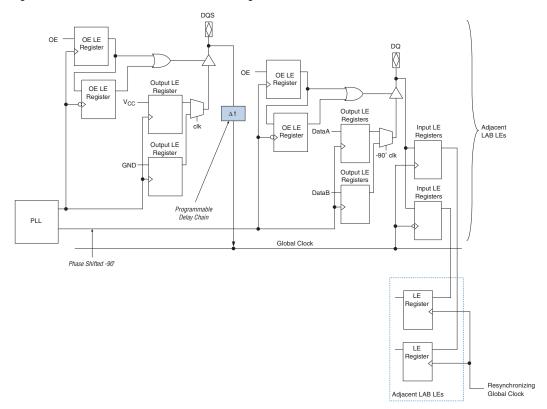


Figure 2-34. DDR SDRAM and FCRAM Interfacing

Programmable Drive Strength

The output buffer for each Cyclone device I/O pin has a programmable drive strength control for certain I/O standards. The LVTTL and LVCMOS standards have several levels of drive strength that the designer can control. SSTL-3 class I and II, and SSTL-2 class I and II support a minimum setting, the lowest drive strength that guarantees the $\rm I_{OH}/I_{OL}$

of the standard. Using minimum settings provides signal slew rate control to reduce system noise and signal overshoot. Table 2–11 shows the possible settings for the I/O standards with drive strength control.

Table 2–11. Programmable Drive Strength Note (1)						
I/O Standard	I _{OH} /I _{OL} Current Strength Setting (mA)					
LVTTL (3.3 V)	4					
	8					
	12					
	16					
	24(2)					
LVCMOS (3.3 V)	2					
	4					
	8					
	12(2)					
LVTTL (2.5 V)	2					
	8					
	12					
	16(2)					
LVTTL (1.8 V)	2					
	8					
	12(2)					
LVCMOS (1.5 V)	2					
	4					
	8(2)					

Notes to Table 2–11:

- SSTL-3 class I and II, SSTL-2 class I and II, and 3.3-V PCI I/O Standards do not support programmable drive strength.
- (2) This is the default current strength setting in the Quartus II software.

Open-Drain Output

Cyclone devices provide an optional open-drain (equivalent to an open-collector) output for each I/O pin. This open-drain output enables the device to provide system-level control signals (e.g., interrupt and write-enable signals) that can be asserted by any of several devices.

Figure 3-1. Cyclone JTAG Waveforms TMS TDI TCK t _{JPXZ} t_{JPZX} t_{JPCO} TDO t_{JSH} t_{JSSU} Signal to Be Captured t_{JSCO} t_{JSXZ} t_{JSZX} -Signal to Be Driven

Figure 3–1 shows the timing requirements for the JTAG signals.

Table 3–4 shows the JTAG timing parameters and values for Cyclone devices.

Table 3-	Table 3–4. Cyclone JTAG Timing Parameters and Values									
Symbol	Parameter	Min	Max	Unit						
t_{JCP}	TCK clock period	100	_	ns						
t _{JCH}	TCK clock high time	50	_	ns						
t _{JCL}	TCK clock low time	50	_	ns						
t _{JPSU}	JTAG port setup time	20	_	ns						
t _{JPH}	JTAG port hold time	45	_	ns						
t _{JPCO}	JTAG port clock to output	_	25	ns						
t_{JPZX}	JTAG port high impedance to valid output	_	25	ns						
t_{JPXZ}	JTAG port valid output to high impedance	_	25	ns						
t _{JSSU}	Capture register setup time	20	_	ns						
t _{JSH}	Capture register hold time	45	_	ns						
t_{JSCO}	Update register clock to output	_	35	ns						
t _{JSZX}	Update register high impedance to valid output	_	35	ns						
t _{JSXZ}	Update register valid output to high impedance	_	35	ns						

Operating Modes

The Cyclone architecture uses SRAM configuration elements that require configuration data to be loaded each time the circuit powers up. The process of physically loading the SRAM data into the device is called configuration. During initialization, which occurs immediately after configuration, the device resets registers, enables I/O pins, and begins to operate as a logic device. Together, the configuration and initialization processes are called command mode. Normal device operation is called user mode.

SRAM configuration elements allow Cyclone devices to be reconfigured in-circuit by loading new configuration data into the device. With real-time reconfiguration, the device is forced into command mode with a device pin. The configuration process loads different configuration data, reinitializes the device, and resumes user-mode operation. Designers can perform in-field upgrades by distributing new configuration files either within the system or remotely.

A built-in weak pull-up resistor pulls all user I/O pins to V_{CCIO} before and during device configuration.

The configuration pins support 1.5-V/1.8-V or 2.5-V/3.3-V I/O standards. The voltage level of the configuration output pins is determined by the V_{CCIO} of the bank where the pins reside. The bank V_{CCIO} selects whether the configuration inputs are 1.5-V, 1.8-V, 2.5-V, or 3.3-V compatible.

Configuration Schemes

Designers can load the configuration data for a Cyclone device with one of three configuration schemes (see Table 3–5), chosen on the basis of the target application. Designers can use a configuration device, intelligent controller, or the JTAG port to configure a Cyclone device. A low-cost configuration device can automatically configure a Cyclone device at system power-up.

Multiple Cyclone devices can be configured in any of the three configuration schemes by connecting the configuration enable (nCE) and configuration enable output (nCEO) pins on each device.

Table 3–5. Data Sources for Configuration							
Configuration Scheme	Data Source						
Active serial	Low-cost serial configuration device						
Passive serial (PS)	Enhanced or EPC2 configuration device, MasterBlaster or ByteBlasterMV download cable, or serial data source						
JTAG	MasterBlaster or ByteBlasterMV download cable or a microprocessor with a Jam or JBC file						

Referenced Documents

This chapter references the following document:

- AN 39: IEEE Std. 1149.1 (JTAG) Boundary-Scan Testing in Altera Devices
- Jam Programming & Test Language Specification

Document Revision History

Table 3–6 shows the revision history for this chapter.

Date and Document Version	Document Changes Made Version				
May 2008 v1.4	Minor textual and style changes. Added "Referenced Documents" section.	_			
January 2007 v1.3	 Added document revision history. Updated handpara note below Table 3–4. 	_			
August 2005 V1.2	Minor updates.	_			
February 2005 V1.1	Updated JTAG chain limits. Added information concerning test vectors.	_			
May 2003 v1.0	Added document to Cyclone Device Handbook.	_			

Table 4–16. Cyclone Device Capacitance Note (14)									
Symbol	Parameter	Typical	Unit						
C _{IO}	Input capacitance for user I/O pin	4.0	pF						
C _{LVDS}	Input capacitance for dual-purpose LVDS/user I/O pin	4.7	pF						
C _{VREF}	Input capacitance for dual-purpose V _{REF} /user I/O pin.	12.0	pF						
C _{DPCLK}	Input capacitance for dual-purpose DPCLK/user I/O pin.	4.4	pF						
C _{CLK}	Input capacitance for CLK pin.	4.7	pF						

Notes to Tables 4–1 through 4–16:

- (1) Refer to the Operating Requirements for Altera Devices Data Sheet.
- (2) Conditions beyond those listed in Table 4–1 may cause permanent damage to a device. Additionally, device operation at the absolute maximum ratings for extended periods of time may have adverse affects on the device.
- (3) Minimum DC input is -0.5 V. During transitions, the inputs may undershoot to -2.0 V or overshoot to 4.6 V for input currents less than 100 mA and periods shorter than 20 ns.
- (4) Maximum V_{CC} rise time is 100 ms, and V_{CC} must rise monotonically.
- (5) All pins, including dedicated inputs, clock, I/O, and JTAG pins, may be driven before V_{CCINT} and V_{CCIO} are powered.
- (6) Typical values are for $T_A = 25^{\circ}$ C, $V_{CCINT} = 1.5$ V, and $V_{CCIO} = 1.5$ V, 1.8 V, 2.5 V, and 3.3 V.
- (7) V_I = ground, no load, no toggling inputs.
- (8) This value is specified for normal device operation. The value may vary during power-up. This applies for all V_{CCIO} settings (3.3, 2.5, 1.8, and 1.5 V).
- (9) R_{CONF} is the measured value of internal pull-up resistance when the I/O pin is tied directly to GND. R_{CONF} value will be lower if an external source drives the pin higher than V_{CCIO}.
- (10) Pin pull-up resistance values will lower if an external source drives the pin higher than V_{CCIO}.
- (11) Drive strength is programmable according to values in Cyclone Architecture chapter in the Cyclone Device Handbook.
- (12) Overdrive is possible when a 1.5 V or 1.8 V and a 2.5 V or 3.3 V input signal feeds an input pin. Turn on "Allow voltage overdrive" for LVTTL/LVCMOS input pins in the Assignments > Device > Device and Pin Options > Pin Placement tab when a device has this I/O combination. However, higher leakage current is expected.
- (13) The Cyclone LVDS interface requires a resistor network outside of the transmitter channels.
- (14) Capacitance is sample-tested only. Capacitance is measured using time-domain reflections (TDR). Measurement accuracy is within ±0.5 pF.

Typically, the user-mode current during device operation is lower than the power-up current in Table 4–17. Altera recommends using the Cyclone Power Calculator, available on the Altera web site, to estimate the user-mode I_{CCINT} consumption and then select power supplies or regulators based on the higher value.

Timing Model

The DirectDrive technology and MultiTrack interconnect ensure predictable performance, accurate simulation, and accurate timing analysis across all Cyclone device densities and speed grades. This section describes and specifies the performance, internal, external, and PLL timing specifications.

All specifications are representative of worst-case supply voltage and junction temperature conditions.

Preliminary and Final Timing

Timing models can have either preliminary or final status. The Quartus® II software issues an informational message during the design compilation if the timing models are preliminary. Table 4–18 shows the status of the Cyclone device timing models.

Preliminary status means the timing model is subject to change. Initially, timing numbers are created using simulation results, process data, and other known parameters. These tests are used to make the preliminary numbers as close to the actual timing parameters as possible.

Final timing numbers are based on actual device operation and testing. These numbers reflect the actual performance of the device under worst-case voltage and junction temperature conditions.

Table 4–18. Cyclone Device Timing Model Status								
Device	Device Preliminary	Final						
EP1C3	_	✓						
EP1C4	_	✓						
EP1C6	_	✓						
EP1C12	_	✓						
EP1C20	_	✓						

Performance

The maximum internal logic array clock tree frequency is limited to the specifications shown in Table 4–19.

Table 4–19. Clock Tree Maximum Performance Specification											
Parameter	Definition	-6 Speed Grade		-7 Speed Grade			-8 S	Unito			
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
Clock tree f _{MAX}	Maximum frequency that the clock tree can support for clocking registered logic		_	405	_	_	320		_	275	MHz

Table 4–20 shows the Cyclone device performance for some common designs. All performance values were obtained with the Quartus II software compilation of library of parameterized modules (LPM) functions or megafunctions. These performance values are based on EP1C6 devices in 144-pin TQFP packages.

Table 4–20. Cyclone Device Performance								
		R	esources U	sed	Performance			
Resource Used	Design Size and Function	Mode	LEs	M4K Memory Bits	M4K Memory Blocks	-6 Speed Grade (MHz)	-7 Speed Grade (MHz)	-8 Speed Grade (MHz)
LE	16-to-1 multiplexer	_	21	_	_	405.00	320.00	275.00
	32-to-1 multiplexer	_	44	_	_	317.36	284.98	260.15
	16-bit counter	_	16	_	_	405.00	320.00	275.00
	64-bit counter (1)	_	66	_	_	208.99	181.98	160.75

Table 4–24. Routing Delay Internal Timing Microparameter Descriptions					
Symbol Parameter					
t _{R4}	Delay for an R4 line with average loading; covers a distance of four LAB columns				
t _{C4}	Delay for an C4 line with average loading; covers a distance of four LAB rows				
t _{LOCAL}	Local interconnect delay				

Figure 4–1 shows the memory waveforms for the M4K timing parameters shown in Table 4–23.

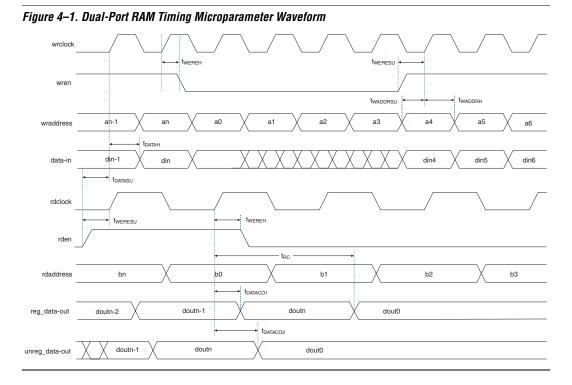


Table 4–45. Cyclone I/O Standard Output Delay Adders for Slow Slew Rate on Row Pins (Part 2 of 2)								
L/O Otandard	-6 Speed Grade		-7 Speed Grade		-8 Speed Grade		II.a.i4	
I/O Standard	Min	Max	Min	Max	Min	Max	- Unit	
SSTL-3 class I	_	1,390	_	1,598	_	1,807	ps	
SSTL-3 class II	_	989	_	1,137	_	1,285	ps	
SSTL-2 class I	_	1,965	_	2,259	_	2,554	ps	
SSTL-2 class II	_	1,692	_	1,945	_	2,199	ps	
LVDS	_	802	_	922	_	1,042	ps	

Note to Tables 4–40 through 4–45:

Tables 4–46 through 4–47 show the adder delays for the IOE programmable delays. These delays are controlled with the Quartus II software options listed in the Parameter column.

Parameter	Setting	-6 Speed Grade		-7 Speed Grade		-8 Speed Grade		Unit
rataillelet		Min	Max	Min	Max	Min	Max	Unit
Decrease input delay to	Off	_	155	_	178	_	201	ps
internal cells	Small	_	2,122	_	2,543	_	2,875	ps
	Medium	_	2,639	_	3,034	_	3,430	ps
	Large	_	3,057	_	3,515	_	3,974	ps
	On	_	155	_	178	_	201	ps
Decrease input delay to	Off	_	0	_	0	_	0	ps
input register	On	_	3,057	_	3,515	_	3,974	ps
Increase delay to output	Off	_	0	_	0	_	0	ps
pin	On	_	552	_	634	_	717	ps

⁽¹⁾ EP1C3 devices do not support the PCI I/O standard.

Table 4–49. Cyclone Maximum Input Clock Rate for Row Pins						
I/O Standard	-6 Speed Grade	-7 Speed Grade	-8 Speed Grade	Unit		
LVTTL	464	428	387	MHz		
2.5 V	392	302	207	MHz		
1.8 V	387	311	252	MHz		
1.5 V	387	320	243	MHz		
LVCMOS	405	374	333	MHz		
SSTL-3 class I	405	356	293	MHz		
SSTL-3 class II	414	365	302	MHz		
SSTL-2 class I	464	428	396	MHz		
SSTL-2 class II	473	432	396	MHz		
3.3-V PCI (1)	464	428	387	MHz		
LVDS	567	549	531	MHz		

Note to Tables 4–48 through 4–49:

Tables 4–50 and 4–51 show the maximum output clock rate for column and row pins in Cyclone devices.

Table 4–50. Cyclone Maximum Output Clock Rate for Column Pins						
I/O Standard	-6 Speed Grade	-7 Speed Grade	-8 Speed Grade	Unit		
LVTTL	304	304	304	MHz		
2.5 V	220	220	220	MHz		
1.8 V	213	213	213	MHz		
1.5 V	166	166	166	MHz		
LVCMOS	304	304	304	MHz		
SSTL-3 class I	100	100	100	MHz		
SSTL-3 class II	100	100	100	MHz		
SSTL-2 class I	134	134	134	MHz		
SSTL-2 class II	134	134	134	MHz		
LVDS	320	320	275	MHz		

Note to Table 4-50:

(1) EP1C3 devices do not support the PCI I/O standard.

⁽¹⁾ EP1C3 devices do not support the PCI I/O standard. These parameters are only available on row I/O pins.

February 2005 v1.1	Updated Figure 5-1.	_
May 2003 v1.0	Added document to Cyclone Device Handbook.	_